

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

FDH50N50

FEATURES

- · With TO-247 packaging
- · With low gate drive requirements
- · Easy to drive
- 100% avalanche tested
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

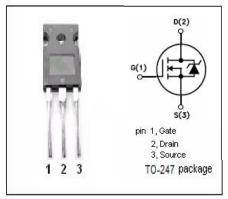
· Switching applications

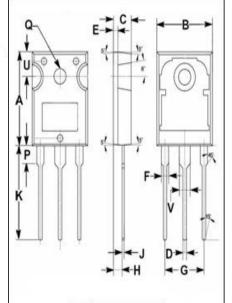
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)					
SYMBOL	PARAMETER	VALUE	UNIT		
V _{DSS}	Drain-Source Voltage	500	v		
V _{GSS}	Gate-Source Voltage ±20		v		
ID	Drain Current-Continuous 48		A		
I _{DM}	Drain Current-Single Pulsed 19		A		
P _D	Total Dissipation	625	w		
Tj	Operating Junction Temperature	-55~150	°C		
Tstg	Storage Temperature	-55~150	°C		

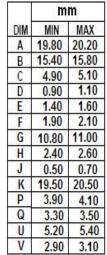
THERMAL CHARACTERISTICS

SYMBOL	MBOL PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.2	°C /W	

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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	500			v
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	3.0		5.0	v
$R_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	V _{GS} = 10V; I _D =24A		89	105	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 500V; V _{GS} = 0V;@Tc=25°C V _{DS} = 400V; V _{GS} = 0V;Tc=125°C			25 250	μA
V_{SDF}	Diode forward voltage	I _{SD} =48A, V _{GS} = 0V			1.4	v

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